

2MBI300XHA120-50

IGBT Modules

Power Module (X series)
1200V / 300A / 2-in-1 package

■ **Features**

- LOW $V_{CE(sat)}$
- High speed switching
- Low Inductance Module structure

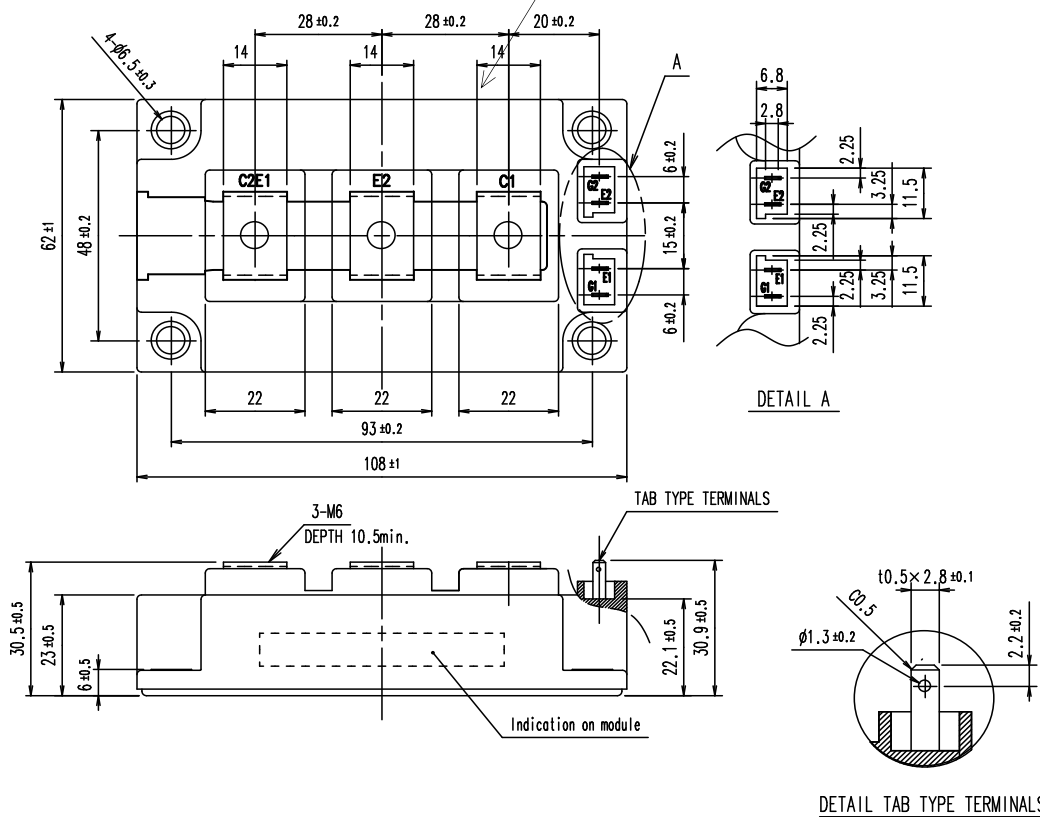
■ **Applications**

- Inverter for Motor Drives, AC and DC Servo Drives
- Uninterruptible Power Supply Systems,
- Industrial machines, such as Welding machines



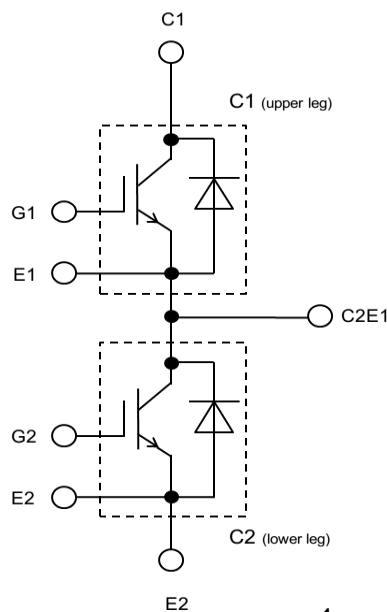
■ **Outline drawing (Unit : mm)**

Characteristics indication



Weight: 370 g(typ.)

■ **Equivalent Circuit**



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■ Absolute Maximum Ratings (at $T_C=25^\circ\text{C}$ unless otherwise specified)

Items		Symbols	Conditions	Maximum Ratings	Units	
Inverter	Collector-Emitter voltage	V_{CES}		1200	V	
	Gate-Emitter voltage	V_{GES}		± 20	V	
	Collector current	I_C	Continuous	$T_C=100^\circ\text{C}$	300	A
		I_{CRM}	1ms		600	
	Forward current	I_F			300	
		I_{FRM}	1ms		600	
	Collector power dissipation	P_c	1 device		1425	W
	Junction temperature	T_{vj}			175	°C
	Operating virtual junction temperature (under switching conditions)	T_{vjop}			175	
	Case temperature	T_c			125	
Storage temperature	T_{stg}			-40 ~ 125		
Isolation voltage	between terminal and copper base (*1)	V_{isol}	AC: 1min.	4000	Vrms	
Screw torque (*2)	Mounting	-	M5	6.0	N·m	
	Terminals		M5	5.0		

(*1) All terminals should be connected together during the test.

(*2) Recommendable Value: Mounting 3.0 ~ 6.0 N·m (M5 or M6)
 Terminals 2.5 ~ 5.0 N·m (M6)

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■ Electrical characteristics (at $T_{vj}= 25^{\circ}\text{C}$ unless otherwise specified)

Items	Symbols	Conditions	Characteristics			Units			
			min.	typ.	max.				
Zero Gate voltage collector current	I_{CES}	$V_{GE} = 0\text{V}$ $V_{CE} = 1200\text{V}$	-	-	200	μA			
Gate-Emitter leakage current	I_{GES}	$V_{CE}=0\text{V}, V_{GE}=\pm 20\text{V}$	-	-	400	nA			
Gate-Emitter threshold voltage	$V_{GE(th)}$	$V_{CE} = 20\text{V}$ $I_C = 300\text{mA}$	6.0	6.5	7.0	V			
Collector-Emitter saturation voltage	$V_{CE(sat)}$ (terminal)	$V_{GE} = 15\text{V}$ $I_C = 300\text{A}$	$T_{vj}=25^{\circ}\text{C}$	-	1.55	2.00	V		
			$T_{vj}=25^{\circ}\text{C}$	-	1.45	1.90			
	$T_{vj}=125^{\circ}\text{C}$		-	1.80	-				
	$T_{vj}=150^{\circ}\text{C}$		-	1.90	-				
	$T_{vj}=175^{\circ}\text{C}$		-	1.95	-				
Internal Gate resistance	r_g	-	-	3.75	-	Ω			
			Capacitance	C_{ies}	$V_{CE}=10\text{V}, V_{GE}=0\text{V}, f=1\text{MHz}$	-	32	-	nF
						C_{oes}	-	1.1	
C_{res}	-	0.29					-		
Gate charge	Q_G	$V_{CC} = 600\text{V}, I_C = 300\text{A}$ $V_{GE} = -15 \rightarrow +15\text{V}$	-	2050	-	nC			
Forward voltage	V_F (terminal)	$V_{GE} = 0\text{V}$ $I_F = 300\text{A}$	$T_{vj}=25^{\circ}\text{C}$	-	1.70	2.15	V		
			$T_{vj}=25^{\circ}\text{C}$	-	1.60	2.05			
	$T_{vj}=125^{\circ}\text{C}$		-	1.65	-				
	$T_{vj}=150^{\circ}\text{C}$		-	1.60	-				
	$T_{vj}=175^{\circ}\text{C}$		-	1.60	-				
Switching time (*1)	$t_{d(on)}$	$V_{CC} = 600\text{V}$ $I_C, I_F = 300\text{A}$ $V_{GE} = +15/-15\text{V}$ $R_G = 1.8 \Omega$ $L_S = 30 \text{ nH}$	$T_{vj}=25^{\circ}\text{C}$	-	395	-	ns		
			$T_{vj}=125^{\circ}\text{C}$	-	425	-			
			$T_{vj}=150^{\circ}\text{C}$	-	430	-			
			$T_{vj}=175^{\circ}\text{C}$	-	425	-			
	t_r		$T_{vj}=25^{\circ}\text{C}$	-	90	-			
			$T_{vj}=125^{\circ}\text{C}$	-	100	-			
			$T_{vj}=150^{\circ}\text{C}$	-	105	-			
			$T_{vj}=175^{\circ}\text{C}$	-	110	-			
	$t_{d(off)}$		$T_{vj}=25^{\circ}\text{C}$	-	335	-			
			$T_{vj}=125^{\circ}\text{C}$	-	375	-			
			$T_{vj}=150^{\circ}\text{C}$	-	385	-			
			$T_{vj}=175^{\circ}\text{C}$	-	405	-			
	t_f		$T_{vj}=25^{\circ}\text{C}$	-	150	-			
			$T_{vj}=125^{\circ}\text{C}$	-	205	-			
			$T_{vj}=150^{\circ}\text{C}$	-	220	-			
			$T_{vj}=175^{\circ}\text{C}$	-	255	-			
Reverse recovery time	t_{rr}	$T_{vj}=25^{\circ}\text{C}$	-	330	-				
		$T_{vj}=125^{\circ}\text{C}$	-	590	-				
		$T_{vj}=150^{\circ}\text{C}$	-	660	-				
		$T_{vj}=175^{\circ}\text{C}$	-	710	-				

(*1) Turn on time (t_{on}) = $t_{d(on)} + t_r$, Turn off time (t_{off}) = $t_{d(off)} + t_f$

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■ Electrical characteristics (at $T_{vj}= 25^{\circ}\text{C}$ unless otherwise specified)

Items	Symbols	Conditions	Characteristics			Units	
			min.	typ.	max.		
Inverter Switching loss (per pulse)	E_{on}	$V_{CC} = 600\text{V}$ $I_C, I_F = 300\text{A}$ $V_{GE} = +15/ -15\text{V}$ $R_G = 1.8 \Omega$ $L_S = 30 \text{ nH}$	$T_{vj}=25^{\circ}\text{C}$	-	25.4	-	mJ
			$T_{vj}=125^{\circ}\text{C}$	-	37.8	-	
			$T_{vj}=150^{\circ}\text{C}$	-	40.9	-	
			$T_{vj}=175^{\circ}\text{C}$	-	45.6	-	
	E_{off}		$T_{vj}=25^{\circ}\text{C}$	-	18.3	-	
			$T_{vj}=125^{\circ}\text{C}$	-	23.6	-	
			$T_{vj}=150^{\circ}\text{C}$	-	25.0	-	
			$T_{vj}=175^{\circ}\text{C}$	-	27.0	-	
	E_{rr}		$T_{vj}=25^{\circ}\text{C}$	-	7.3	-	
			$T_{vj}=125^{\circ}\text{C}$	-	14.1	-	
			$T_{vj}=150^{\circ}\text{C}$	-	15.8	-	
			$T_{vj}=175^{\circ}\text{C}$	-	18.4	-	

NOTICE:

The external gate resistance (R_G) shown above is one of our recommended value for the purpose of minimum switching loss. However the optimum R_G depends on circuit configuration and/or environment. We recommend that the R_G has to be carefully chosen based on consideration if IGBT module matches design criteria, for example, switching loss, EMC/EMI, spike voltage, surge current and no unexpected oscillation and so on.

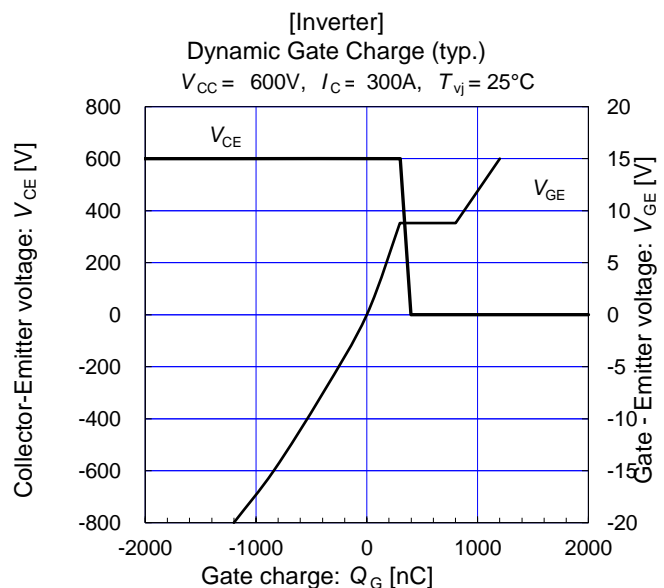
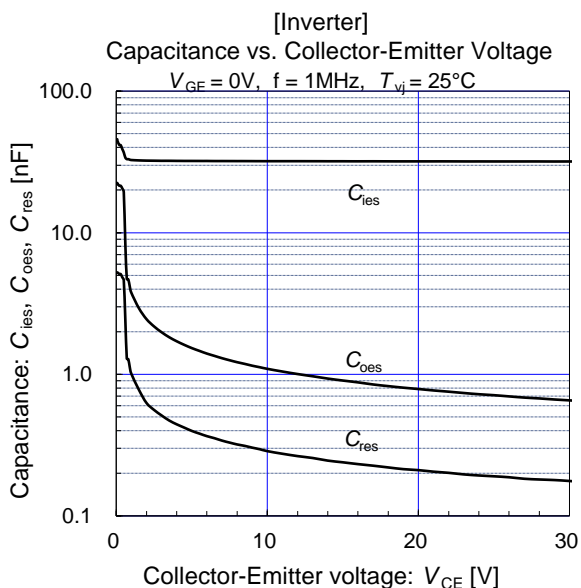
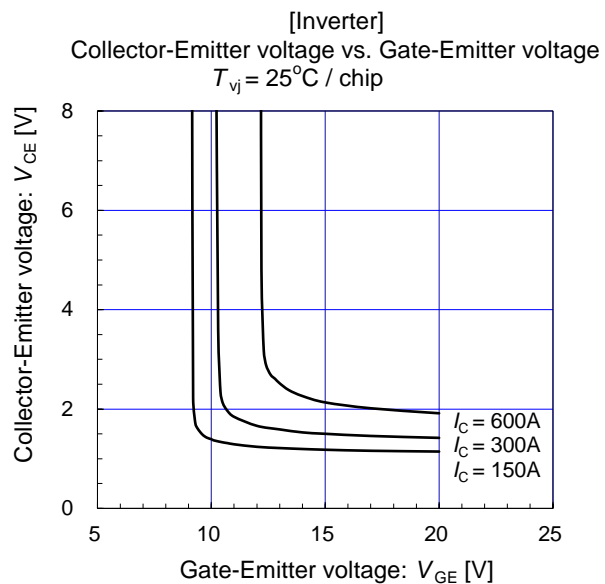
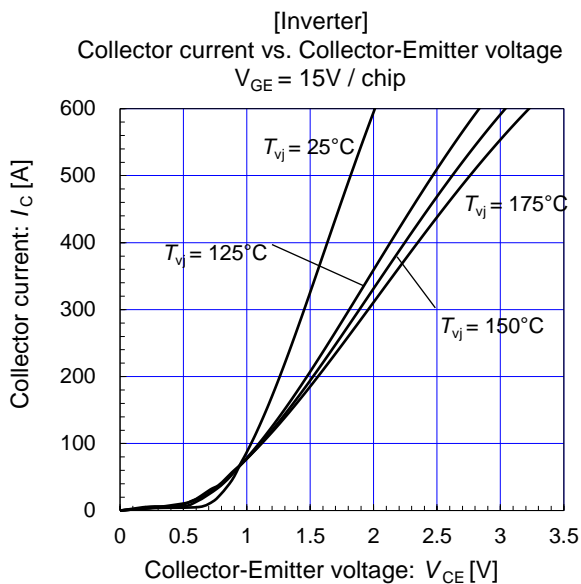
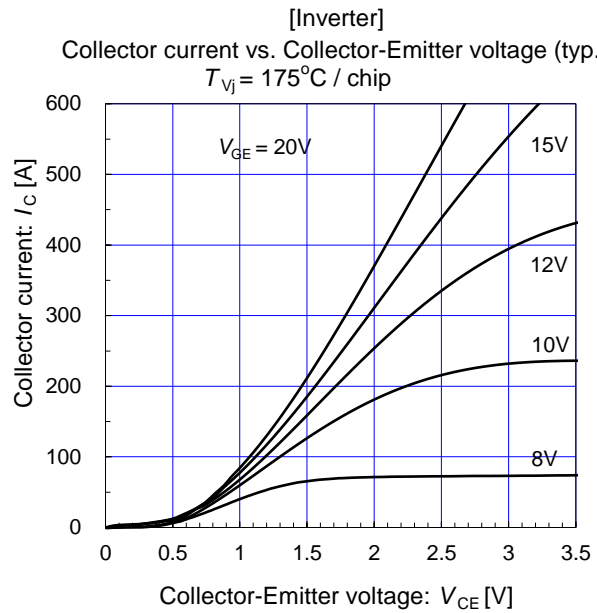
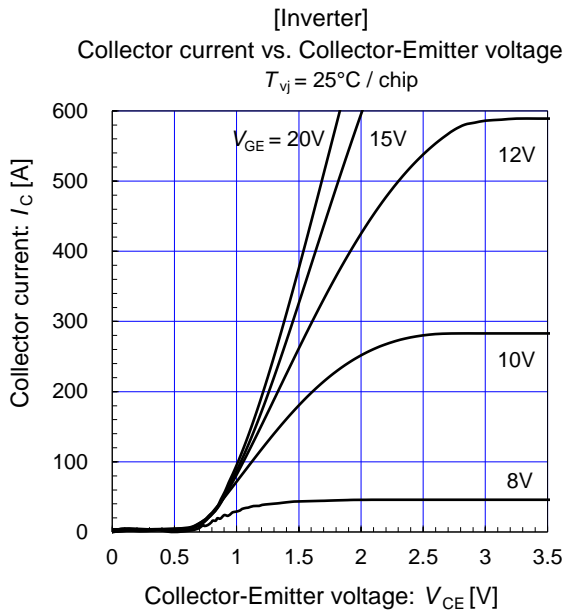
■ Thermal resistance characteristics

	Symbols	Conditions	Characteristics			ns
			min.	typ.	max.	
Thermal resistance junction to case (1 device)	$R_{th(j-c)}$	IGBT	-	-	0.105	$^{\circ}\text{C/W}$
		FWD	-	-	0.165	
Thermal resistance case to heat sink (1IGBT + 1FWD) (*1)	$R_{th(c-s)}$	with 1 W/(m·K) thermal grease	-	0.0125	-	

(*1) This is the value which is defined mounting on the additional cooling fin with thermal compound.

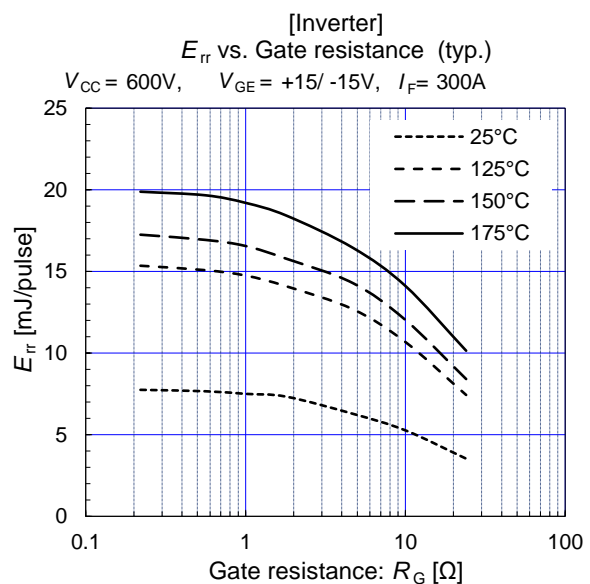
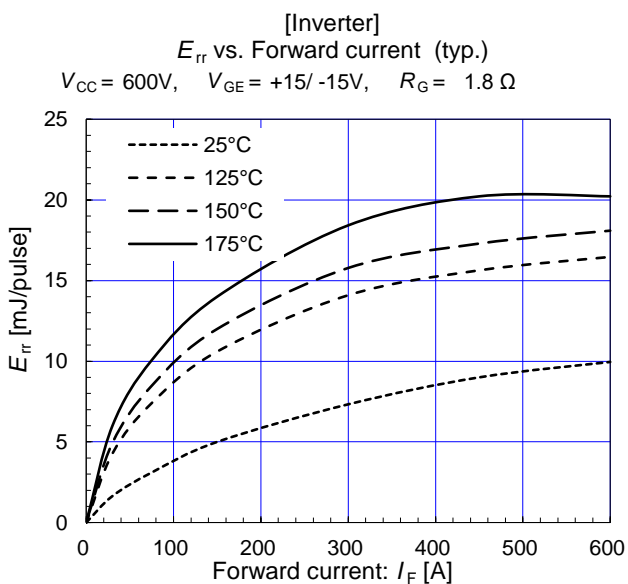
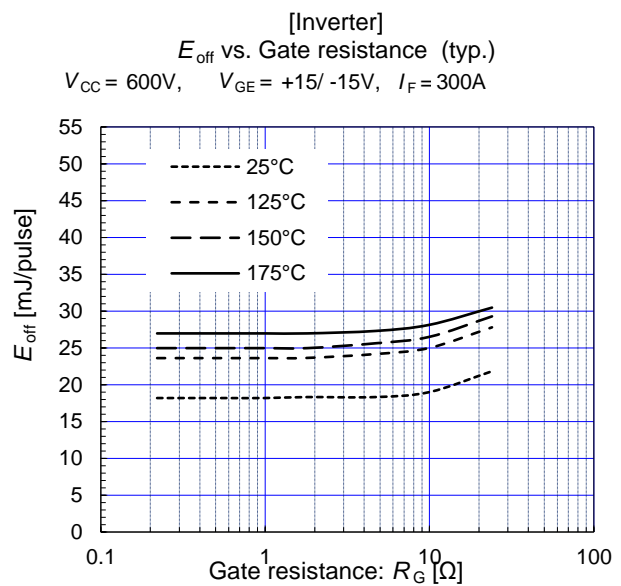
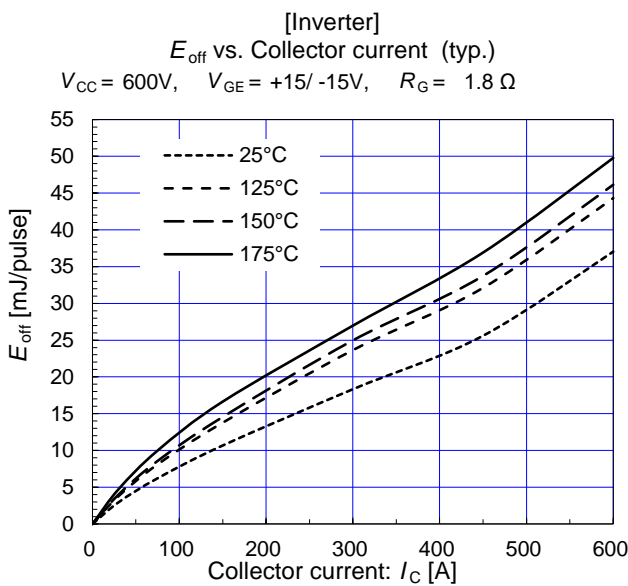
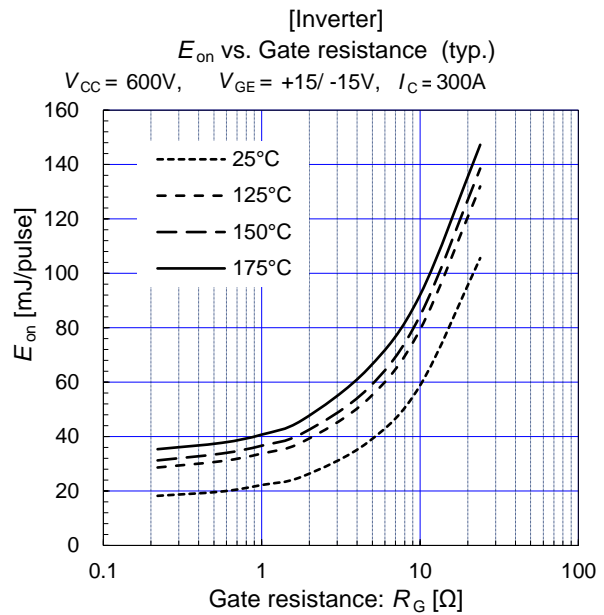
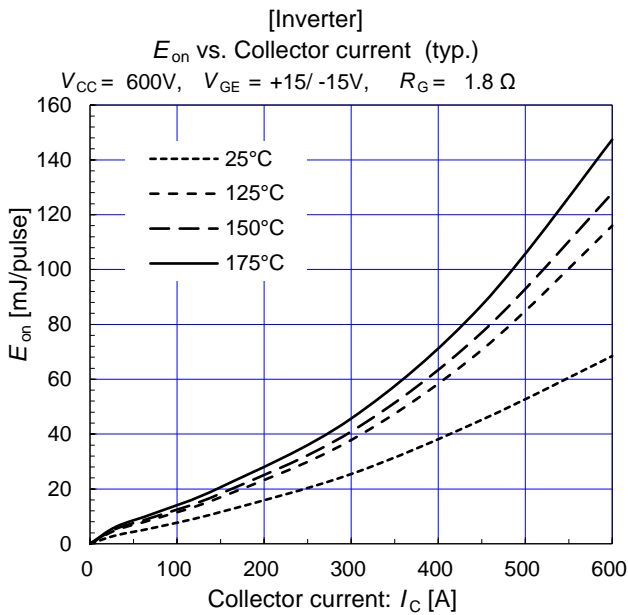
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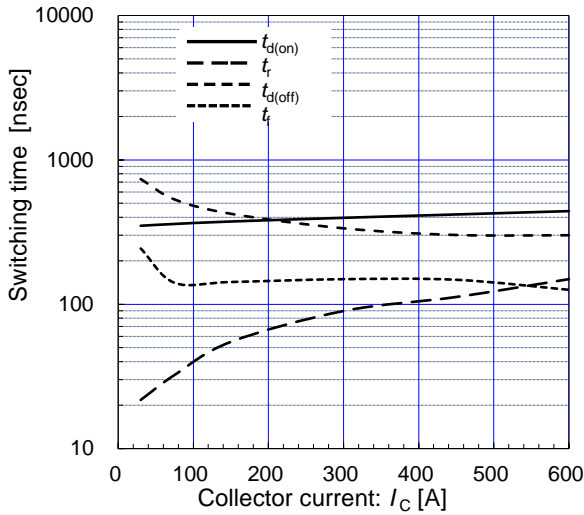
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[Inverter]

Switching time vs. Collector current (typ.)

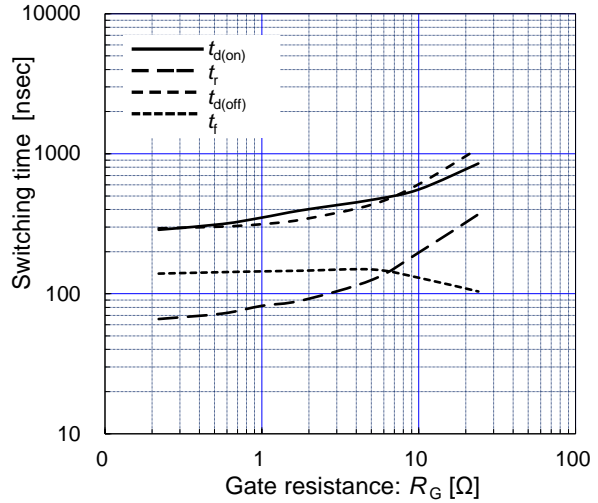
$V_{CC} = 600V, R_G = 1.8 \Omega, V_{GE} = +15/-15V, T_{vj} = 25^\circ C$



[Inverter]

Switching time vs. Gate resistance (typ.)

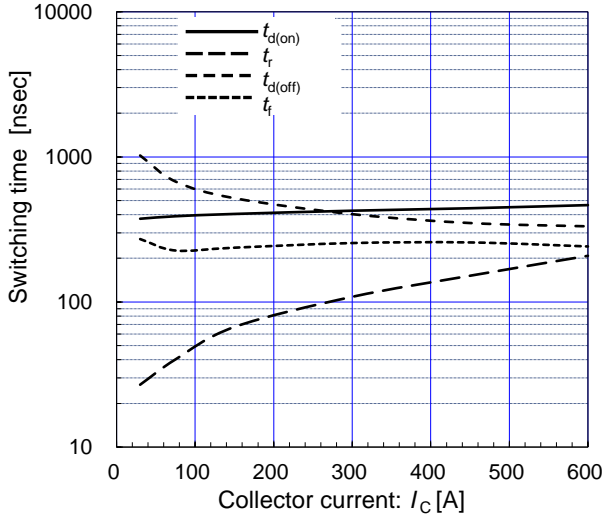
$V_{CC} = 600V, I_C = 300A, V_{GE} = +15/-15V, T_{vj} = 25^\circ C$



[Inverter]

Switching time vs. Collector current (typ.)

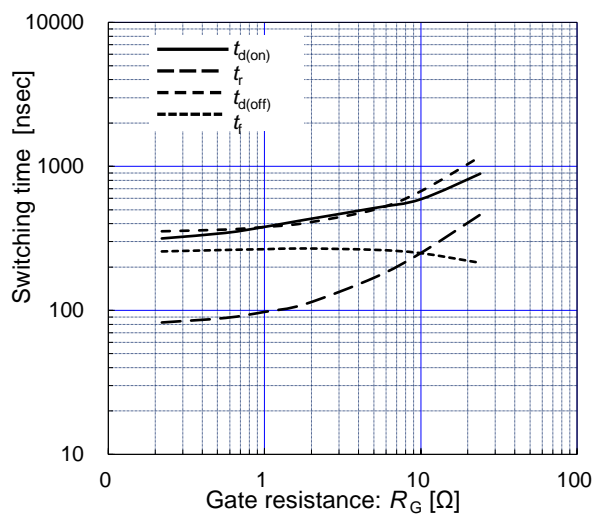
$V_{CC} = 600V, R_G = 1.8 \Omega, V_{GE} = +15/-15V, T_{vj} = 175^\circ C$



[Inverter]

Switching time vs. Gate resistance (typ.)

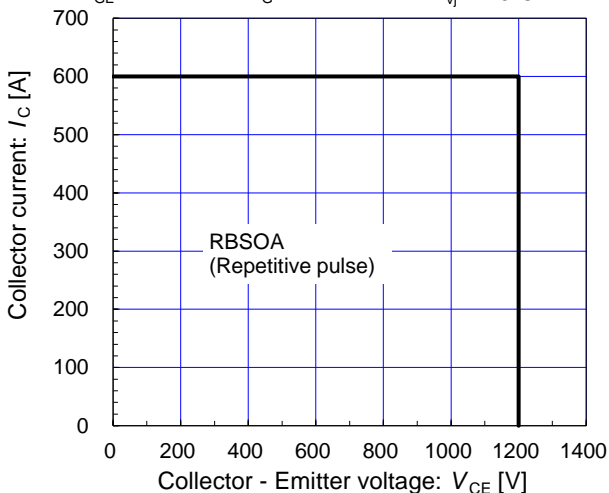
$V_{CC} = 600V, I_C = 300A, V_{GE} = +15/-15V, T_{vj} = 175^\circ C$



[Inverter]

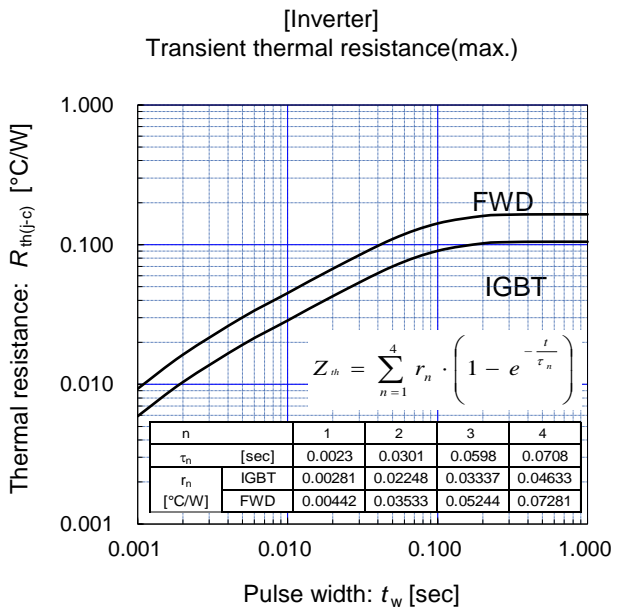
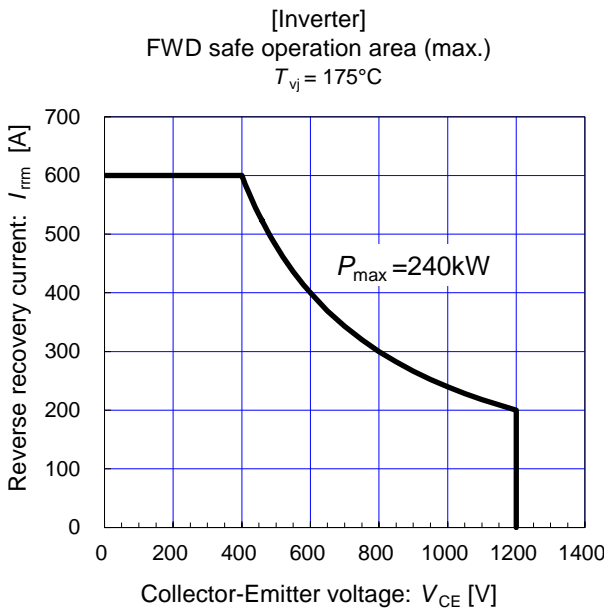
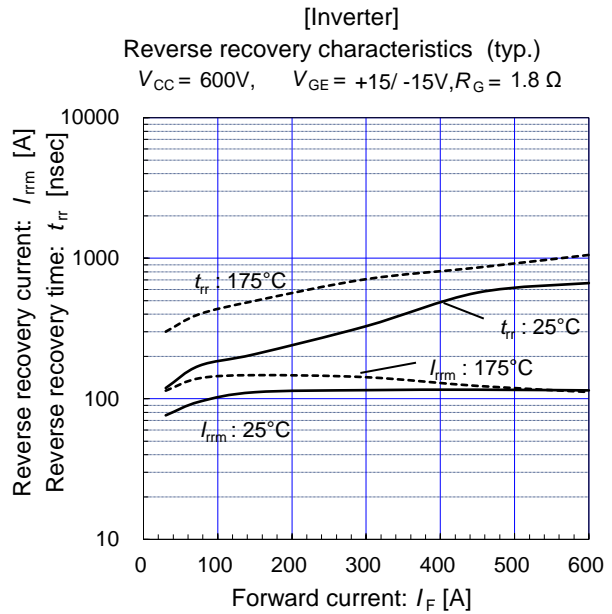
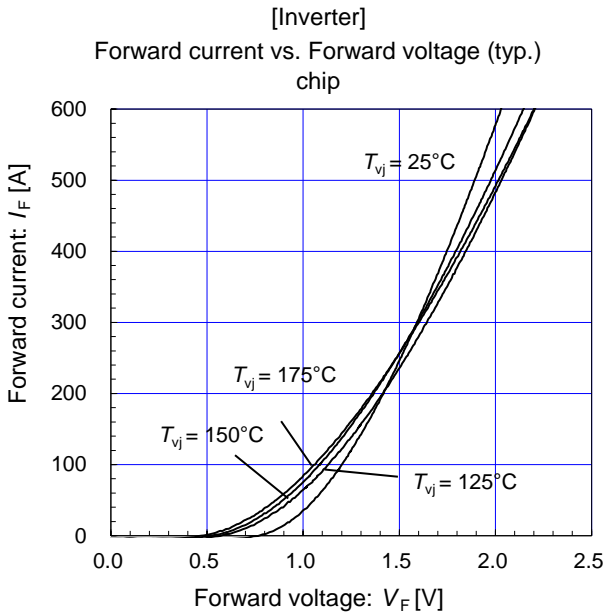
Reverse bias safe operating area (max.)

$V_{GE} = +15/-15V, R_G = 1.8 \Omega, T_{vj} = 175^\circ C$



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